

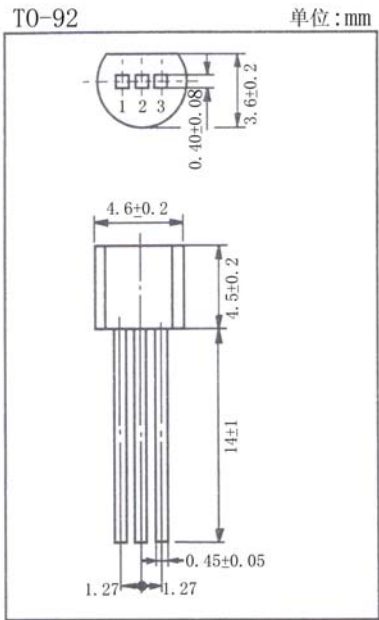
MJE13002H1 (3DD13002H1)硅 NPN 半导体三极管/SILICON NPN TRANSISTOR

用途：主要用于节能灯、日光灯电子镇流器及其它开关、振荡电路。

Purpose: High frequency electronic lighting ballast applications, converters, inverters, switching regulators, etc.

极限参数/Absolute maximum ratings(Ta=25℃)

参数符号 Symbol	数值 Rating	单位 Unit
V _{CB0}	600	V
V _{CE0}	400	V
V _{EB0}	9.0	V
I _C	1.2	A
P _C (Ta=25℃)	1.0	W
T _j	150	℃
T _{stg}	-55~150	℃



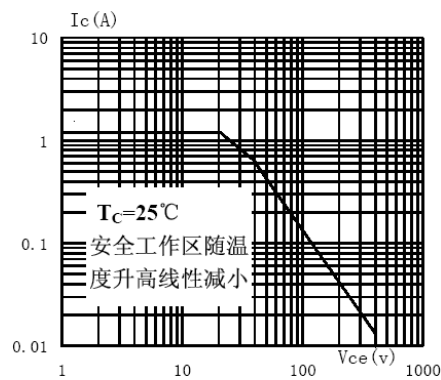
引脚：1. E 2. C 3. B

电性能参数/Electrical characteristics(Ta=25℃)

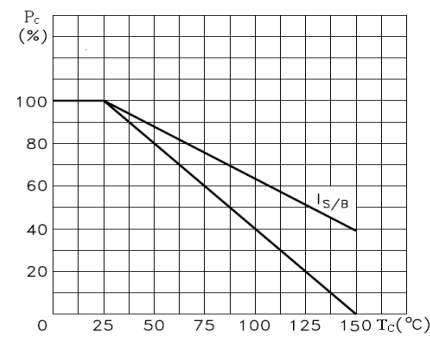
参数符号 Symbol	测试条件 Test condition		数值 Rating			单位 Unit
			最小值 Min	典型值 Typ	最大值 Max	
V _{CB0}	I _C =1mA I _E =0		600			V
V _{CE0}	I _C =10mA I _B =0		400			V
V _{EB0}	I _E =1mA I _C =0		9.0			V
I _{CB0}	V _{CB} =600V I _E =0				0.1	mA
I _{CE0}	V _{CE} =400V I _B =0				0.1	mA
I _{EB0}	V _{EB} =9.0V I _C =0				0.1	mA
h _{FE}	V _{CE} =5.0V I _C =200mA		10		40	
V _{CE(sat)}	I _C =500mA I _B =100mA				0.8	V
V _{BE(sat)}	I _C =500mA I _B =100mA				1.2	V
f _T	V _{CE} =10V I _C =100mA f=1.0MHz		5.0			MHz
t _f	V _{CE} =5V I _C =250mA				0.6	μs
t _S	(UI9600)				3.5	μs

MJE13002H1 (3DD13002H1)

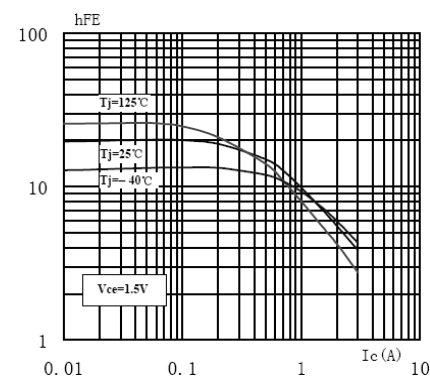
SOA (DC)



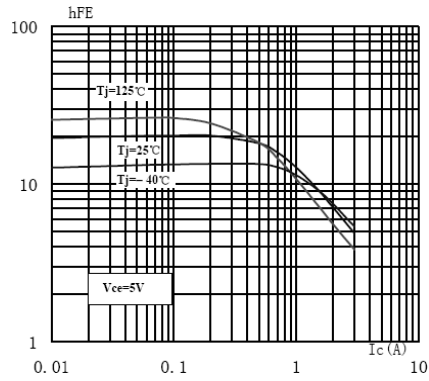
Pc-Tc



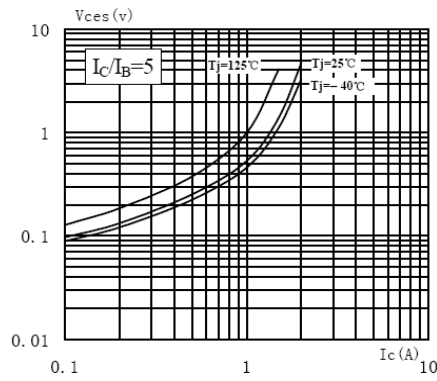
hFE-Ic



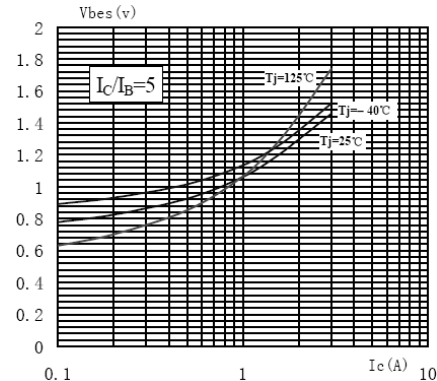
hFE-Ic



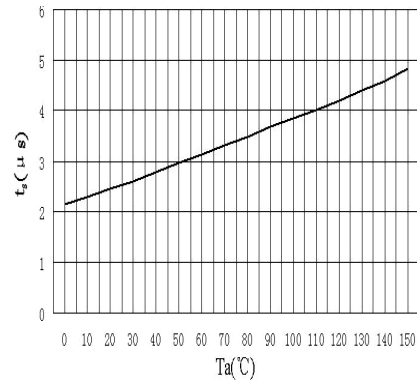
Vces-Ic



Vbes-Ic



ts-Ta



hFE-Ta

